

Synchrotrons for condensed matter physics and materials science: Research snippets and an outlook

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## Magnetic & electronic phase transitions at high pressure

### Antiferromagnetism in chromium

VOLUME 19, NUMBER 15

PHYSICAL REVIEW LETTERS

9 October 1967

#### PRESSURE DEPENDENCE OF ITINERANT ANTIFERROMAGNETISM IN CHROMIUM

D. B. McWhan and T. M. Rice

Bell Telephone Laboratories, Murray Hill, New Jersey

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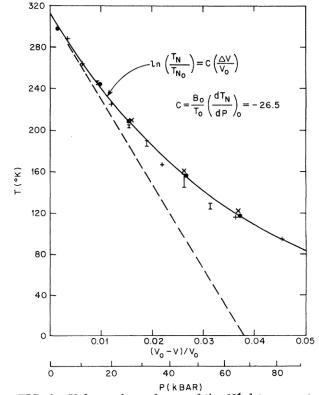


FIG. 1. Volume dependence of the Néel temperature of chromium. Vertical bars, sample 1; crosses, sample 2; and solid circles, sample 3.

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#### PHYSICAL REVIEW B

#### VOLUME 51, NUMBER 16

#### X-ray-scattering study of charge- and spin-density waves in chromium

J. P. Hill, G. Helgesen,\* and Doon Gibbs

Department of Physics, Brookhaven National Laboratory, Upton, New York 11973 (Received 28 September 1994; revised manuscript received 19 December 1994)

We report an x-ray-scattering study of the incommensurate modulations in pure chromium. X magnetic scattering from the spin-density wave (SDW) is observed. No resonant enhancement of the nal is obtained near the Cr K edge. On cooling through the spin-flip transition, the magnetic signal to zero, consistent with the polarization dependence of nonresonant magnetic scattering and the knopplarization of the SDW. Charge scattering is observed at the second harmonic due to the associal charge-density wave (CDW). The intensity of the second harmonic is unchanged on cooling through spin-flip transition. A survey of possible second-harmonic satellites reveals that a single Q state exist the near-surface region. The amplitude of the lattice distortion is estimated to  $(\Delta_2/a)=1.5\pm0.2\times10^{-3}$ , consistent with published reports. A fourth harmonic is also observed, a gesting that the CDW is not perfectly sinusoidal. The intensity of the fourth harmonic is 0.05% of second and we find  $(\Delta_4/a)=2.8\pm0.2\times10^{-5}$ . The temperature dependence of the charge harmonics is found to obey mean-field scaling.

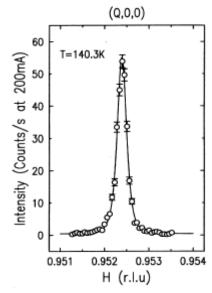
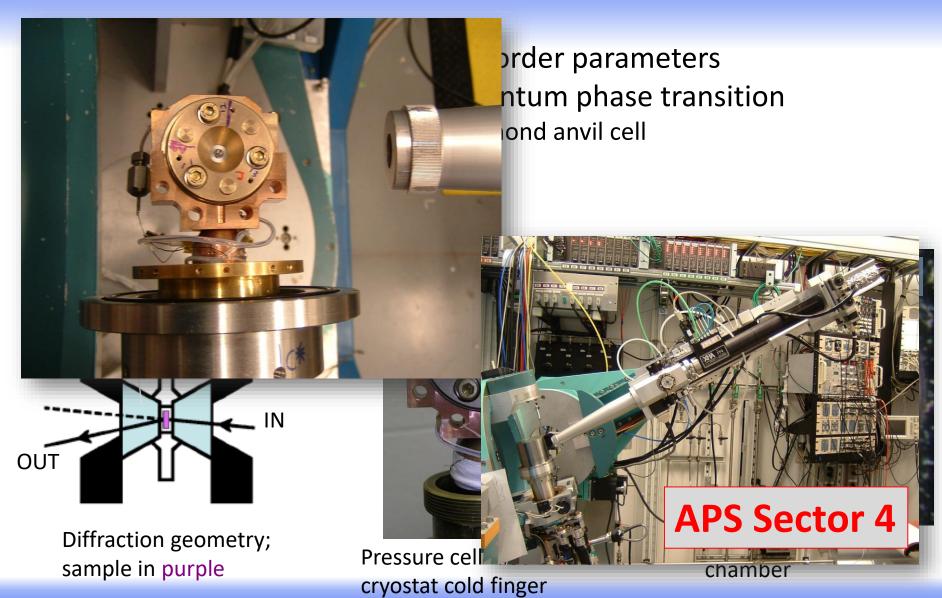


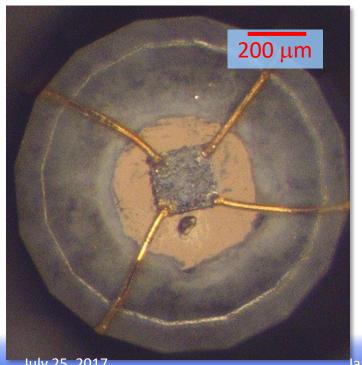
FIG. 2. Longitudinal scan through the SDW peak. These data were taken on a wiggler beamline at E = 5.91 keV, just below the Cr K edge at T = 140.3 K.

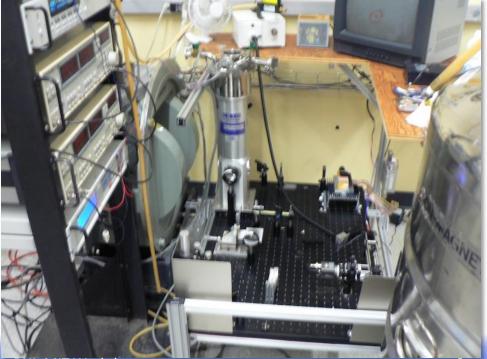
#### Experiment – High Pressure X-Ray Diffraction



### Experiment – High Pressure Transport

- Resistivity + Hall coefficient
  - Sensitive to metallic DOS
  - Carrier scattering from critical fluctuations
- Magnetotransport in a DAC
  - van der Pauw geometry → four leads in the sample chamber
  - Magnetic field + fluorescence spectrometry + in situ pressure control

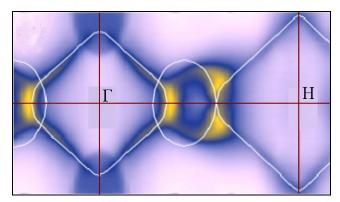




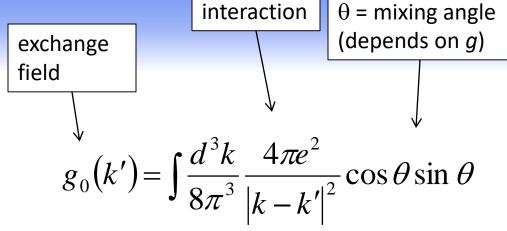
ıly 25*,* 2017

Ground state of antiferromagnetic chromium

- Equation for exchange field is analogous to the BCS gap equation
- SDW remains stable for arbitrarily weak interaction provided that the nested phase space remains large



Photoemission measurement of paramagnetic Fermi surface in (011) plane; Rotenberg *et al.*, New J. Phys. **7**, 114 (2005).

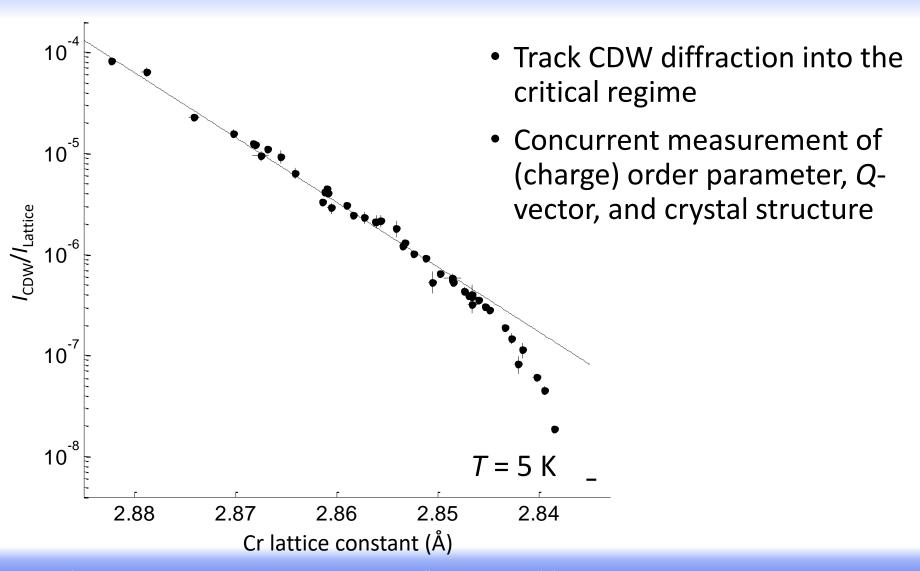


- replace interaction with a constant
- model two nested bands
- expand for small  $g/E_F$

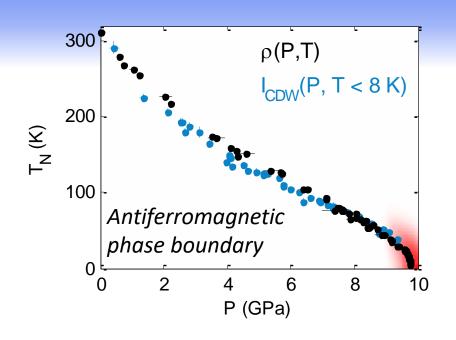
$$g_0 \propto T_N \propto e^{-1/\lambda}, \lambda = \frac{\gamma^2 V k_c^2}{2\pi^2 v}$$

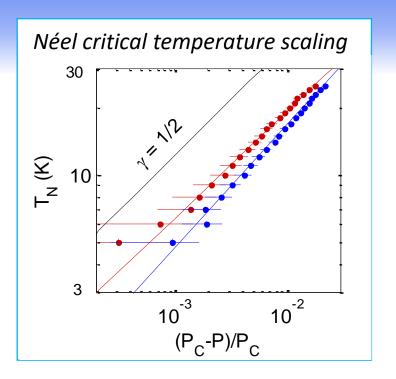
 $\gamma$  = exchange integral V = Coulomb potential  $4\pi k_c^2$  = nesting area v = average Fermi velocity

## Weak-coupling ground state and the quantum critical regime



#### Combined X-ray and electrical results





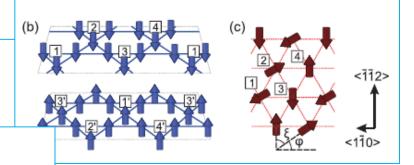
- Electrical results support phase diagram determined by CDW diffraction
- Measure scaling relationships between pressure,  $T_N$ , resistivity, and Hall coefficient
  - All consistent with mean-field Fermi surface reconstruction

### Technique development is enabling!

PHYSICAL REVIEW B 86, 014422 (2012)

Pressure tuning of competing magnetic interactions in intermetallic CeFe<sub>2</sub>

Jiyang Wang, <sup>1</sup> Yejun Feng, <sup>1,2,\*</sup> R. Jaramillo, <sup>3</sup> Jasper van Wezel, <sup>4</sup> P. C. Canfield, <sup>5</sup> and T. F. Rosenbaum <sup>1</sup>



## Order parameter fluctuations at a buried quantum critical point

Yejun Feng<sup>a,b,1</sup>, Jiyang Wang<sup>b</sup>, R. Jaramillo<sup>c</sup>, Jasper van Wezel<sup>d</sup>, S. Haravifard<sup>a,b</sup>, G. Srajer<sup>a</sup>, Y. Liu<sup>e,f</sup>, Z.-A. Xi P. B. Littlewood<sup>g</sup>, and T. F. Rosenbaum<sup>b,1</sup>

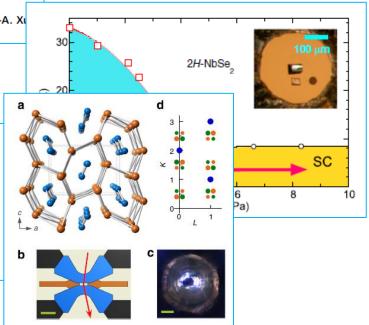
#### **ARTICLE**

Received 29 Mar 2014 | Accepted 27 May 2014 | Published 18 Jun 2014

DOI: 10.1038/ncomms5218

Hidden one-dimensional spin modulation in a three-dimensional metal

Yejun Feng<sup>1,2</sup>, Jiyang Wang<sup>2</sup>, A. Palmer<sup>2</sup>, J.A. Aguiar<sup>3</sup>, B. Mihaila<sup>3,4</sup>, J.-Q. Yan<sup>5,6</sup>, P.B. Littlewood<sup>2,7</sup> & T.F. Rosenbaum<sup>2</sup>





## Opportunities for synchrotrons in materials science

## A user's perspective















### Unassailable advantages of X-rays

1. Contrast modes

Crystallography

Local structure

Collective excitations

Morphology

Fast dynamics

Composition

Bandstructure & quasiparticle spectroscopy

Slow dynamics

Chemistry

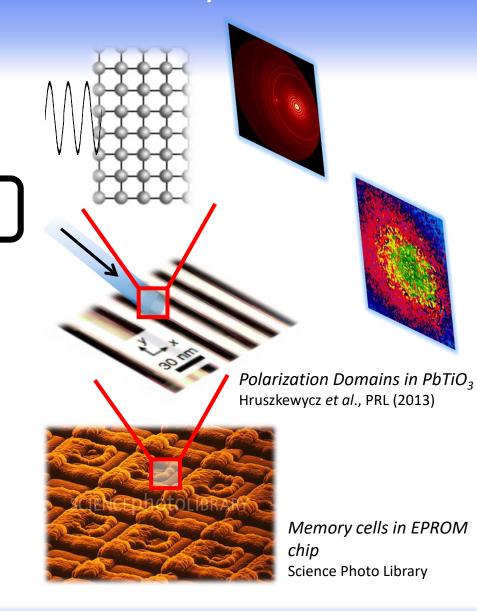
### Unassailable advantages of X-rays

2. Field of view

Atomic scale ↔ X-ray wavelength

Macroscale ↔ Scanning probe

Mesoscale ↔ Focused beam



### Unassailable advantages of (hard) X-rays

#### 3. *In situ* capabilities

	PVD/CVD	Micro- electronics	Solar Cell	Thermo- electrics	Catalysis	Batteries	Fuel Cell
Temperature (°C)	300-600	0-300	500-1500	500-1000	400-2000	~500	600-1000
Pressure	10 <sup>-8</sup> – 1 atm	1 atm	1 atm	1 atm	1 atm	1 atm	1-5 atm
Length Scale (Defect - Device)	Å - μm	nm - cm	nm - cm	nm - cm	Å - cm	nm - mm	nm - mm

### The importance of field-of-view

Standard (1500ms/pt) step scan, 10 µm/pixel 0.8 x 0.8 mm<sup>2</sup>



Multichannel detector (5ms/pt) slew scan, 10 μm/pixel 13.5 x 13.5 mm<sup>2</sup>



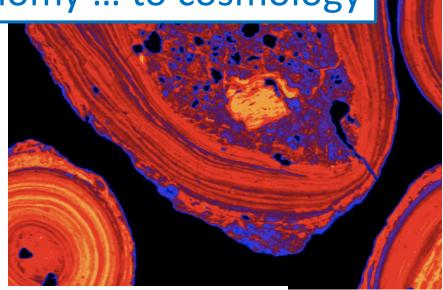
Data from studies and related presentations of:

D.P. Siddons et al.

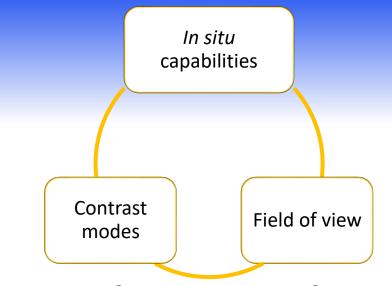
DOI: 10.1017/S1431927605510298

C.G. Ryan et al.

DOI: 10.1016/j.nima.2009.11.035



Iron-oxide nodules, Rose Dam, WA



## Combining these advantages...

## Spectromicroscopy & mesoscale electronic heterogeneity

*In situ* capabilities

Field of

view

Contrast

modes

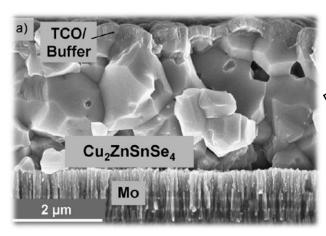
**XPS** 

sample

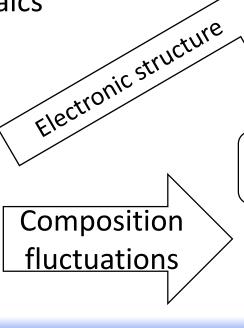
Correlate composition, spectra
 & function in inhomogeneous
 materials

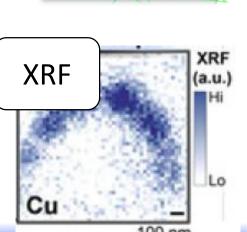
Compound semiconductors

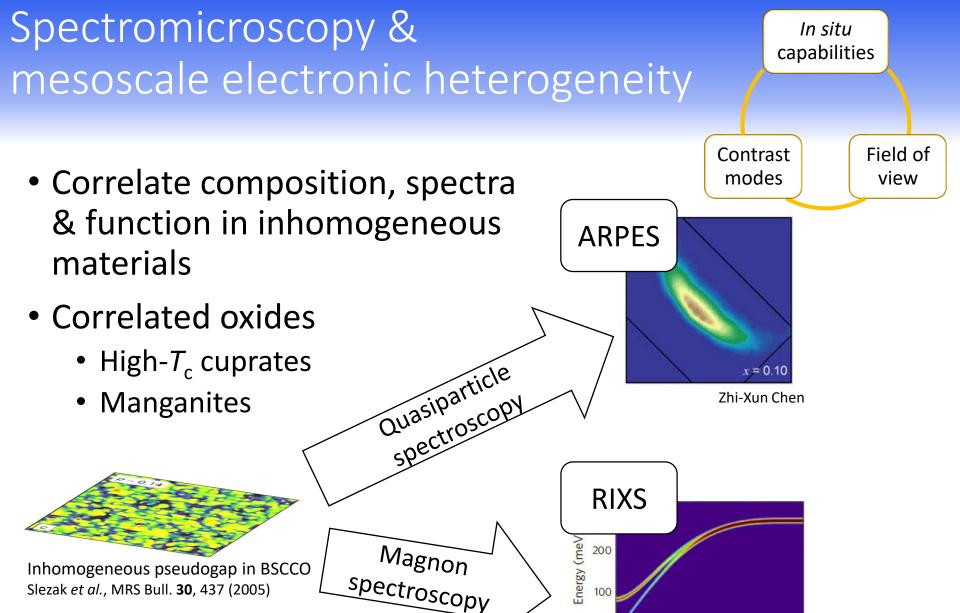
• Thin film photovoltaics



CZTS solar cell Todorov *et al.*, Adv. Mater. **22**, E156 (2010).







Le Tacon et al., Nat. Phys. 7, 725 (2011)

0.4

0.3

0.2

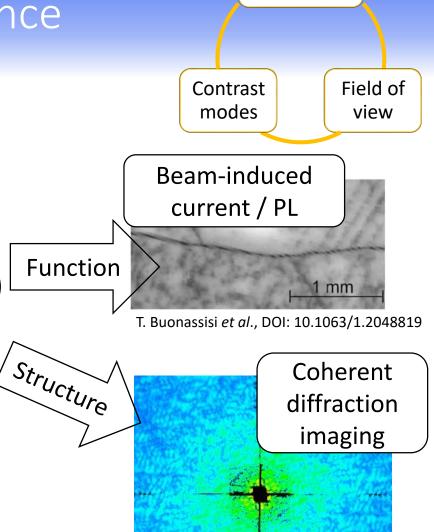
Q<sub>II</sub>(r.l.u.)

## Materials processing, extended defects & device performance

 Microscopic view of materials synthesis & processing

 Connect structure of extended defects to function (PL, current)

- Applications in
  - Heteroepitaxy (e.g. III-V on Si)
  - Passivation
  - Degradation & failure analysis



*In situ* capabilities

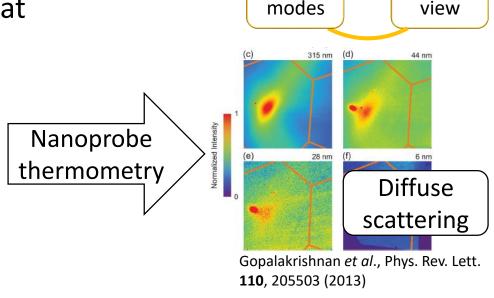
Heat transport and non-equilibrium device physics

*In situ* capabilities

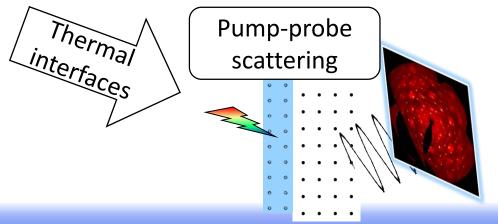
Field of

 Microscopic understanding of heat generation & transport

- Phonon spectra in confined & disordered materials
- Interface resistance
- Ballistic & diffusive transport
- Outstanding questions in
  - Thermoelectrics
  - Thermal management
  - Microelectronics scaling



Contrast



Warning: Incoherent

## Thoughts on building productive institutional relationships

## From CATs and super-users ... to "just" another tool in the materials science kit

#### The olden days

- Beamlines built and run by collaborative access teams (CATs), with significant university involvement
- PIs were often synchrotron super-users and formed strong relationships with CATs

#### Today

- Expense and scope of beamline development prices out the CAT model and creates incentive to broaden user base
- User facility model now includes expectation of ease-of-use and quick answers

### Synchrotron ambassadors

- Who are the synchrotron ambassadors at MIT?
  - In this room
  - Busy
- Who are the X-ray ambassadors at MIT?

CMSE

XRD facility managers

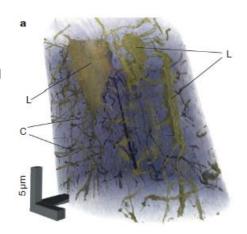
X-ray Diffraction Shared Experimental Facility

- What is the role of a synchrotron ambassador?
  - Turning hero experiments ... ... into metrology
  - Electron microscopy community seems better at this

### Success hinges on usability

- Success will hinge on all aspects of the tool
  - Spot size and coherence are enabling factors
  - End-station usability
  - Superb sample environments
  - Accessible, specialized and powerful computing
- Lens-less imaging (ptychography + tomography) must become standard
  - Near-term: everyone should be able to do it, given an honest effort (like Reitvelt refinement?)
  - Medium-term: everyone should be able to do it, given minimal effort (like SEM?)





Dierolf et al., Nature 467, 436 (2010)

# Jaramillo Research Group Electronic Materials



## Opportunities in chalcogenide electronic materials

#### Sensing

- Defect-engineering to customize photoresponse
- Alternative processes for sulfide & selenide film growth for IR

#### Neuromorphic

 Excitation & inhibition of opto-electronic contrast through defect-engineering

#### Photovoltaics & photochemistry

 Defect-tolerant semiconductor alloys with tunable band gap

#### Solid state chemistry & physics

Chalcogenide perovskites & similarly complex, ionic structures

